## **Supporting Information for**

## Gate-Controllable Quadri-Layertronics in 2D Multiferroic Antiferromagnet

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Fig. S1 (a) Crystal structures, (b) band structure and spin direction, and (c) Berry curvatures of the AAAA configuration of quadrilayer lattice with  $M_z$  symmetry.



**Fig. S2** Low-energy band dispersions near the K and K' valleys based on the  $k \cdot p$  model for the (a) ABCA, (b) ACBA, (c) ABAC, (d) ABCB and (e) AAAA configurations of quadrilayer lattice.



**Fig. S3** (a) Top view and (b) side view of single-layer  $OsCl_2$ , where the dashed box in (a) represents the unit cell, and the balls of blue and gray label the Cl and Os atoms, respectively. (c) Coordinate atom around Os atom constituting the local structure of  $OsCl_6$ . (d) The first Brillouin zone. (e) Schematic illustration of energy level splitting of *d* orbitals caused by trigonal prism crystal field, the distribution of six *d* electrons of cation Os in energy level shows a high-spin state.



**Fig. S4** (a) Phonon spectrums of single-layer OsCl<sub>2</sub>. (b) Band structures of single-layer OsCl<sub>2</sub> with SOC. Blue and red lines represent the spin-down and spin-up states. (c) Evolution of the total energy from the 3 ps AIMD simulation at 300 K.



Fig. S5 (a) Anomalous Hall conductivity of the ABCA (solid line) and ACBA (dotted line) stacking configurations. (b) A magnified view of panel (a) focusing on the valence band edge near the Fermi level.(c) Anomalous Hall conductivity of the ABCB (solid line) and ABAC (dotted line) configurations.



Fig. S6 Energy profiles for ferroelectric switching between ABCA and ABCB configurations in quadrilayer OsCl<sub>2</sub>.

**Table S1**. Energy differences between FM and AFM states and magnetocrystalline anisotropy energy of ABCA, ACBA, ABAC, and ABCB configurations of quadrilayer OsCl<sub>2</sub>.

	QL-FM (eV/cell)	QL-AFM (meV/cell)	MAE (eV/cell)
ABCA (ACBA)	0.031	0	0.13
ABAC (ABCB)	0.023	0	0.03

## Methods

First-principles calculations are performed based on density functional theory (DFT) as implemented in the Vienna ab initio simulation package (VASP)<sup>1,2</sup>. The exchange-correlation interaction is treated by the generalized gradient approximation (GGA) in the form of Perdew, Burke, and Ernzerhof (PBE) functional<sup>3</sup>. The convergence criteria for energy and force are set to  $10^{-5}$  eV and 0.01 eV Å<sup>-1</sup>. The cutoff energy is set to 500 eV. A  $13 \times 13 \times 1$  Monkhorst-Pack grid is adopted for k-point sampling. Considering the strong correlations, we use the GGA + *U* approach with  $U_{eff} = (U - J) = 2$  eV for Os-*d* orbital according to previous work<sup>4</sup>. Grimme's DFT-D3 method<sup>5</sup> is included to describe the van der Waals interaction. The Berry curvature is calculated using VASPBERRY<sup>6</sup>. The ferroelectric polarization is evaluated using the Berry phase approach<sup>7</sup>, and the energy barrier of ferroelectric switching is obtained by nudged elastic band (NEB) method<sup>8</sup>.

## References

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